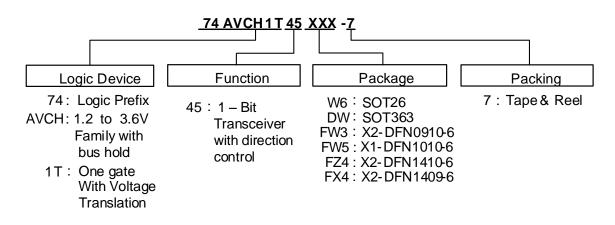


Ordering Information



Part Number	Deekere Cede	Deelegring	7" Tape and	Reel (Note 7)
Part Number	Package Code	Packaging	Quantity	Part Number Suffix
74AVCH1T45W6-7	W6	SOT26	3,000/Tape & Reel	-7
74AVCH1T45DW-7	DW	SOT363	3,000/Tape & Reel	-7
74AVCH1T45FW3-7	FW3	X2-DFN0910-6	5,000/Tape & Reel	-7
74AVCH1T45FW5-7	FW5	X1-DFN1010-6	5,000/Tape & Reel	-7
74AVCH1T45FZ4-7	FZ4	X2-DFN1410-6	5,000/Tape & Reel	-7
74AVCH1T45FX4-7	FX4	X2-DFN1409-6	5,000/Tape & Reel	-7

Notes: 4. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Pin Descriptions

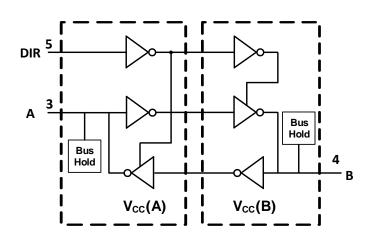
Pin Name	Pin	Function
VCC(A)	1	Supply for I/O pin A and reference for DIR
GND	2	Ground
A	3	Data Input/Output
В	4	Data Input/Output
DIR	5	Direction Control
VCC(B)	6	Supply for I/O pin B

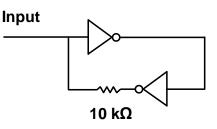
Function Table

Supply voltage	Input	Input/Output			
V _{CC(A)} , V _{CC(B)}	DIR (Direction Pin)	A B			
1.2 V to 3. 6 V	L	A=B	input		
1.2 V to 3. 6 V	Н	input	B=A		
GND	Х	Z	Z		



Logic Diagram





Bus Hold Circuit Previous Input is Latched Input Signals must be strong enough to override 10kΩ

Symbol Parameter Rating Unit ESD HBM Human Body Model ESD Protection 2 kV ESD CDM Charged Device Model ESD Protection kV 1 ESD MM Machine Model ESD Protection 200 V V Vcc(A), Vcc(B) Supply Voltage Range -0.5 to +4.6 -0.5 to +4.6 V Input Voltage Range VI -0.5 to +4.6 V Voltage Applied to Output in High Impedance or IOFF State Vo V -0.5 to V_{CC}(A) +0.5 A pin Vo Voltage Applied to Output in High or Low State B pin V -0.5 to V_{CC}(B) +0.5 $I_{\rm IK}$ Input Clamp Current VI<0 -50 mΑ Output Clamp Current -50 mΑ loĸ lo **Continuous Output Current** ±50 mΑ ±100 mΑ Continuous Current Through V_{CC} or GND °C **Operating Junction Temperature** -40 to +150 ТJ Storage Temperature -65 to +150 °C TSTG

Absolute Maximum Ratings (Note 5) (@T_A = +25°C, unless otherwise specified.)

Note: 5. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Condition (Notes 6, 7 & 8) (@T_A = +25°C, unless otherwise specified.)

Symbol	Para	meter	V _{CCI}	V _{cco}	Min	Max	Units
V _{CC} (A)	Operating Volta	ge	_	_	1.2	3.6	V
V _{CC} (B)	Operating Volta	ge	—	—	1.2	3.6	V
			1.2 to 1.95V	1.2 to 3.6V	0.65 x V _{CC(A)}	_	
VIII	High-Level Input Voltage	Data Inputs	1.95 to 2.7V	1.2 to 3.6V	1.6	_	V
ľ	input voltage		2.7V to 3.6V	1.2 to 3.6V	2	_	
			1.2 to 1.95V	1.2 to 3.6V	_	0.35 x V _{CC(A)}	
Vii	Low-Level Input Voltage	Data Inputs	1.95 to 2.7V	1.2 to 3.6V	_	0.7	V
	input voltago		2.7V to 3.6V	1.2 to 3.6V	_	0.8	
		DIR	1.2 to 1.95V	1.2 to 3.6V	0.65 x V _{CC(B)}	—	
VIII	High-Level Input Voltage	(referenced to	1.95 to 2.7V	1.2 to 3.6V	1.6	—	V
	input voltago	V _{CCA})	2.7 to 3.6V	1.2 to 3.6V	2	_	
		DIR	1.2 to 1.95V	1.2 to 3.6V	_	0.35 x V _{CC(B)}	
Vii	Low-Level	v-Level (referenced to 1.95 to 2.7V 1.2 to 3.6V — 0.7	V				
ľ	input voltage	V _{CCA})	2.7 to 3.6V	1.2 to 3.6V		0.8	
VI I	Input Voltage		_	_	0	3.6	V
	Output Valtage	Active state	_	_	0	Vcco	V
V _o	Output Voltage	3-state	—	—	0	3.6	V
			1.2 to 3.6V	1.2V	_	-3	
			1.2 to 3.6V	1.4 to 1.6V	_	-6	
I _{OH} H	High-Level Outp	out Current	1.2 to 3.6V	1.65 to 1.95V	_	-8	mA
			1.2 to 3.6V	2.3 to 2.7V	_	-9	
			1.2 to 3.6V	3 to 3.6V	_	-12	
			1.2 to 3.6V	1.2V	_	3	
			1.2 to 3.6V	1.4 to 1.6V	_	6	
I _{OL} L	Low-Level Outp	out Current	1.2 to 3.6V	1.65 to 1.95V	_	8	mA
			1.2 to 3.6V	2.3 to 2.7V	_	9	
			1.2 to 3.6V	3 to 3.6V		12	
Δt/ΔV	Input Transition Rate	Rise or Fall	1.2 to 3.6V	1.2 to 3.6V	-	5	ns/V
T _A (Operating Free	Air Temperature			-40	+85	°C

Note:

6. V_{CCO} is the V_{CC} associated with the output port.

7. V_{CCI} is the V_{CC} associated with the input port.

8. All unused inputs of the device must be held at V_{CCI} of GND.



0	Barranta	-)/ (D)	Т	_A = +25°	С	T _A = -40°C	to +85°C	
Symbol	Parameter	I	est Conditions	V _{CC} (A)	V _{CC} (B)	Min	Тур	Max	Min	Max	Unit
		I _{OH} = -1	100μA	1.2 to 3.6V	1.2V to 3.6V	_	_	_	$V_{CC} - 0.2$	-	
		I _{OH} = -3	BmA	1.2V	1.2V	_	0.95	_	_	_	
V	High Level	I _{OH} = -6	SmA	1.4V	1.4V	_	-	_	1.05	_	V
V _{OH}	Output Voltage	I _{OH} = -8	BmA	1.65V	1.65V	_	-	_	1.2	_	V
		I _{OH} = -9mA		2.3V	2.3V	_	-	_	1.75	_	
		I _{OH} = -1	2mA	3V	3V	_	_	_	2.3	_	
		I _{OL} = 10	0μΑ	1.2 to 3.6V	1.2V to 3.6V	_		_	—	0.2	
		$I_{OL} = 3r$	nA	1.2V	1.2V	—	0.15	_	_	_	
	Low-Level Output	$I_{OL} = 6r$	mA	1.4V	1.4V	_	_	_	_	0.35	.,
V _{OL}	Voltage	$I_{OL} = 8r$	nA	1.65V	1.65V	_	_	_	_	0.45	V
		$I_{OL} = 9r$	nA	2.3V	2.3V	—	_	_	_	0.55	
		I _{OL} = 12	2mA	3V	3V	_	_	_	_	0.7	
II.	Input Current	DIR	$V_I = V_{CC}(A)$ or GND	1.2 to 3.6V	1.2 to 3.6V	-0.25	±0.25	0.25	-1	1	μA
I _{OFF}	Power Down	A Pin	V_1 or $V_0 = 0$ to 3.6V	0V	0 to 3.6V	-1	±0.1	1	-5	5	μA
.011	Leakage Current	B Pin		0 to 3.6V	0	-1	±0.1	1	-5	5	ġ,
	3-State Leakage	B Pin	$V_0 = V_{CCO}$ or Gnd	0V	0 to 3.6V	-2.5	±0.5	2.5	-5	5	
loz	Current	A Pin	V _I = V _{CCI} or Gnd	0 to 3.6V	0	-2.5	±0.5	2.5	-5	5	μA
				1.2 to 3.6V	11.2 to 3.6V	_	_	_	_	10	
I _{CCA}	Supply Current		_{CI} or GND	3.6V	0V	_	_	_	_	-2	μA
		$I_{\rm O} = 0$		0V	3.6V	_	_	_	_	10	
				1.2 to 3.6V	1.2 to 3.6V	_	_	_	_	10	
I _{CCB}	Supply Current	-	_{CI} or GND	0V	3.6V	_	_		_	10	μA
		$I_0 = 0$		3.6V	0V	_	_		_	-2	
I _{CCA} + I _{CCB}	Supply Current	$V_I = V_{CCI}$ or GND $I_O = 0$		1.2 to 3.6V	1.2 to 3.6V	_	_	_	_	20	μA
CI	Input Capacitance	DIR V _I = V _{CC} (A) or GND		3.3V	3.3V	_	2.5	_	_	_	pF
CIO	Input/Output Capacitance	A or B pin	V _I = V _{CC} (A)/(B) or GND	3.3V	3.3V	_	6.0	_	_	_	pF

Electrical Characteristics (Notes 9 & 10) (@T_A = +40°C to +85°C, unless otherwise specified.)

Notes: 9. V_{CCO} is the V_{CC} associated with the output port.

10. V_{CCI} is the V_{CC} associated with the input port.



Package Characteristics ($V_{CC} = 3.3V$, $T_A = +25^{\circ}C$, unless otherwise specified.)

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
		SOT26				_	
		SOT363		_	371	_	
0	Thermal Resistance Junction-	X2-DFN0910-6	(Note 11)		530	_	°C/W
θ_{JA}	to-Ambient	X2- DFN1410-6	(Note 11)	_	430	_	°C/vv
		X2-DFN1409-6]		450	_	
		X1-DFN1010-6	-		510	_	
		SOT26		_	46	_	
		SOT363		_	143	_	
0	Thermal Resistance Junction-	X2-DFN0910-6	(Note 11)	_	260	_	°C/W
θ _{JC}	to-Case	X2- DFN1410-6	(Note 11)		190	_	
		X2-DFN1409-6			200	—	
		X1-DFN1010-6		_	250	_	

Note: 11. Test condition for all packages: Device mounted on FR-4 substrate PC board, 2oz copper with minimum recommended pad layout.

Switching Characteristics

Parameter	From (Input)	To (Output)	V _{CC} (B) = 1.2V	V _{CC} (B) = 1.5V ±0.1	V _{CC} (B) = 1.8V ±0.15V	V _{CC} (B) = 2.5V ±0.2V	V _{CC} (B) = 3.3V ±0.3V	Unit
	(input)	(Output)	TYP	ТҮР	TYP	TYP	TYP	
t _{PLH}	A	в	3.3	2.7	2.4	2.3	2.4	ns
t PHL	A	Б	3.3	2.7	2.4	2.3	2.4	115
t _{PLH}	в	А	3.3	3.1	2.9	2.8	2.7	ns
t _{PHL}	В	~	3.3	3.1	2.9	2.8	2.7	115
t _{PHZ}	DIR	А	5.1	5.2	5.3	5.2	3.7	ns
t _{PLZ}	DIK	~	5.1	5.2	5.3	5.2	3.7	115
t _{PHZ}	DIR	в	5.3	4.3	4.0	3.3	3.7	ns
t _{PLZ}	DIK	В	5.3	4.3	4.0	3.3	3.7	115
t _{PZH} *	DIR	А	8.6	7.3	6.8	6.1	6.4	ns
t _{PZL} *	DIK	~	8.6	7.3	6.8	6.1	6.4	115
t _{PZH} *	DIR	в	8.3	7.8	7.7	7.5	5.8	ns
t _{PZL} *		0	8.3	7.8	7.7	7.5	5.8	

 $^{\ast}\textsc{Enable}$ times are calculated vales see table at end of switching characteristics.

 V_{CC} (A) = 1.5V ± 0.1V, T_A = -40°C to +85°C, See Figure 1

Parameter	From (Input)	To (Output)	V _{CC} (B) = 1.2V		= 1.5V 0.1) = 1.8V 15V	V _{CC} (B) = 2.5V ±0.2V		V _{CC} (B) = 3.3V ±0.3V		Unit
	(input)	(Output)	TYP	Min	Max	Min	Max	Min	Max	Min	Max	
t _{PLH}	A	В	2.9	0.7	5.6	0.6	5.2	0.5	4.2	0.5	3.8	ns
t _{PHL}	~	Б	2.9	0.7	5.6	0.6	5.2	0.5	4.2	0.5	3.8	115
t _{PLH}	в	А	2.6	0.6	5.5	0.4	5.3	0.3	4.9	0.3	4.8	ns
t _{PHL}	Б	A	2.6	0.6	5.5	0.4	5.3	0.3	4.9	0.3	4.8	115
t _{PHZ}	DIR	А	3.8	1.6	6.7	1.5	6.8	0.3	6.9	0.9	6.9	ns
t _{PLZ}	DIK	~	3.8	1.6	6.7	1.5	6.8	0.3	6.9	0.9	6.9	115
t _{PHZ}	DIR	В	5.1	1.8	8.1	1.6	7.1	1.1	4.7	1.4	4.5	ns
t _{PLZ}	DIK	Б	5.1	1.8	8.1	1.6	7.1	1.1	4.7	1.4	4.5	115
t _{PZH} *	DIR	А	7.7	_	13.6		12.4	—	9.6	—	9.3	ns
t _{PZL} *	DIK	~	7.7	_	13.6		12.4	—	9.6	—	9.3	115
t _{PZH} *	DIR	В	6.7	_	12.3		12	-	11.1	_	10.7	ns
t _{PZL} *		В	6.7	_	12.3	_	12	_	11.1	_	10.7	115

*Enable times are calculated vales see table at end of switching characteristics.



Switching Characteristics (Continued)

Parameter	From	To	V _{CC} (B) = 1.2V) = 1.5V 0.1		= 1.8V 15V		= 2.5V .2V		= 3.3V .3V	Unit	
	(Input)	(Output)	TYP	Min	Max	Min	Max	Min	Max	Min	Max		
t _{PLH}	А	В	2.7	0.6	5.3	0.5	5.0	0.4	3.9	0.4	3.4	ns	
t PHL	~	Б	2.7	0.6	5.3	0.5	5.0	0.4	3.9	0.4	3.4	115	
t PLH	в	А	2.3	0.5	5.2	0.4	5.0	0.3	4.6	0.2	4.4	ns	
t _{PHL}	Б	~	2.3	0.5	5.2	0.4	5.0	0.3	4.6	0.2	4.4	115	
t _{PHZ}	DIR	А	3.8	1.6	5.9	1.6	5.9	1.6	5.9	0.5	6.0	ns	
t _{PLZ}	DIK	~	3.8	1.6	5.9	1.6	5.9	1.6	5.9	0.5	6.0	115	
t PHZ	DIR	В	5.0	1.8	7.7	1.4	6.8	1.0	4.4	1.4	5.3	ns	
t _{PLZ}	DIK	Б	5.0	1.8	7.7	1.4	6.8	1.0	4.4	1.4	5.3	115	
t _{PZH} *	DIR	А	7.3	_	12.9		11.8	—	9.0		8.7	20	
t _{PZL} *	DIK	A	7.3	—	12.9		11.8	—	9.0		8.7	ns	
t _{PZH} *	PIP	В	6.5	_	11.2	_	10.9	_	9.8	_	9.4	200	
t _{PZL} *	UIR	В	DIR B	6.5	_	11.2	_	10.9	_	9.8		9.4	ns

*Enable times are calculated vales see table at end of switching characteristics.

V_{CC} (A) = 2.5V \pm 0.2V, T_A = -40°C to +85°C, See Figure 1

Parameter	From (Input)	To (Output)	V _{CC} (B) = 1.2V		= 1.5V 0.1) = 1.8V 15V		= 2.5V .2V		= 3.3V .3V	Unit
	(input)	(Output)	TYP	Min	Max	Min	Max	Min	Max	Min	Max]
t _{PLH}	Α	В	2.6	0.5	4.9	0.4	4.6	0.3	3.4	0.3	3.0	20
t _{PHL}	A	Б	2.6	0.5	4.9	0.4	4.6	0.3	3.4	0.3	3.0	ns
t _{PLH}	В	А	2.2	0.4	4.2	0.3	3.8	0.2	3.4	0.2	3.3	ns
t _{PHL}	Б	A	2.2	0.4	4.2	0.3	3.8	0.2	3.4	0.2	3.3	115
t _{PHZ}	DIR	А	2.8	0.3	3.8	0.8	3.8	0.4	3.8	0.5	3.8	-
t _{PLZ}	DIK	A	2.8	0.3	3.8	0.8	3.8	0.4	3.8	0.5	3.8	ns
t _{PHZ}	DIR	В	4.9	2.0	7.6	1.5	6.5	0.6	4.1	1.0	4.0	20
t _{PLZ}	DIR	Б	4.9	2.0	7.6	1.5	6.5	0.6	4.1	1.0	4.0	ns
t _{PZH} *	DIR	А	7.1	_	11.8	_	10.3	—	7.5	_	7.3	
t _{PZL} *	DIR	А	7.1	_	11.8	_	10.3	—	7.5	—	7.3	ns
t _{PZH} *	DIR	В	5.4	_	8.6	_	8.1	—	7.0	—	6.6	-
t _{PZL} *	UIK	В	5.4	_	8.6	_	8.1	—	7.0	—	6.6	ns

*Enable times are calculated vales see table at end of switching characteristics.

V_{CC} (A) = 3.3V \pm 0.3V, T_{A} = -40°C to +85°C, See Figure 1

Parameter	From (Input)	To (Output)	V _{CC} (B) = 1.2V	,) = 1.5V 0.1) = 1.8V 15V		= 2.5V .2V) = 3.3V .3V	Unit
	(input)	(Output)	TYP	Min	Max	Min	Max	Min	Max	Min	Max	
t _{PLH}	A	В	2.6	0.4	4.7	0.3	4.4	0.2	3.3	0.2	2.8	20
t _{PHL}	A	Б	2.6	0.4	4.7	0.3	4.4	0.2	3.3	0.2	2.8	ns
tPLH	в	А	2.2	0.4	3.8	0.3	3.4	0.2	3	0.1	2.8	20
t _{PHL}	В	A	2.2	0.4	3.8	0.3	3.4	0.2	3	0.1	2.8	ns
t _{PHZ}	DIR	^	3.1	1.3	4.3	1.3	4.3	1.3	4.3	1.3	4.3	20
t _{PLZ}	DIR	A	3.1	1.3	4.3	1.3	4.3	1.3	4.3	1.3	4.3	ns
t _{PHZ}	DIR	В	4	0.7	7.4	0.6	6.5	0.7	4	1.5	4.9	20
t _{PLZ}	DIR	Б	4	0.7	7.4	0.6	6.5	0.7	4	1.5	4.9	ns
t _{PZH} *		^	6.2	_	11.2	—	9.9	—	7	—	6.7	
t _{PZL} *	DIR	A	6.2	_	11.2	—	9.9	—	7	—	6.7	ns
t _{PZH} *		Р	5.7	_	8.9	_	8.5	—	7.2	_	6.8	-
t _{PZL} *	DIR	DIR B -	5.7	_	8.9	—	8.5	—	7.2	—	6.8	ns

*Enable times are calculated vales see table at end of switching characteristics.



Enable Time Calculations

Enable times can be calculated as follows:

- t_{PZH} (DIR to A) = t_{PLZ} (DIR to B) + t_{PLH} (B to A)
- t_{PZL} (DIR to A) = t_{PHZ} (DIR to B) + t_{PHL} (B to A)
- t_{PZH} (DIR to B) = t_{PLZ} (DIR to A) + t_{PLH} (A to B)
- t_{PZL} (DIR to B) = t_{PHZ} (DIR to A) + t_{PHL} (A to B)

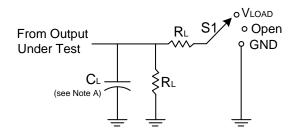
These times represent the length of time from a direction change plus the propagation time through the part. A new input signal should not be applied until the new input pin has been disabled.

Operating Characteristics (T_A = +25°C, unless otherwise specified.)

	Parameter sipation Capacitance	Test Conditions	V _{CC} (A) = V _{CC} (B) = 1.8V Typ	V _{CC} (A) = V _{CC} (B) = 2.5V Typ	V _{CC} (A) = V _{CC} (B) = 3.3V Typ	V _{CC} (A) = V _{CC} (B) = 5V Typ	Unit
	A- input, B- output	$C_L = 0 pF$	3	4	4	4	
C _{PD} (A)	B- input, A- output	f = 10 MHz tr = tf = 1 ns	18	19	20	21	pF
	A- input, B- output	$C_L = 0 pF$	18	19	20	21	
C _{PD} (B)	B- input, A- output	f = 10 MHz tr = tf = 1 ns	3	4	4	4	pF

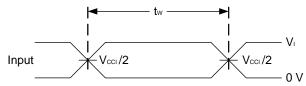


Parameter Measurement Information

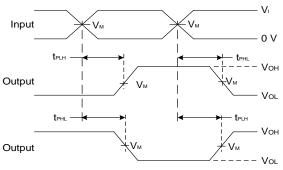


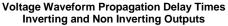
TEST	S1
t _{PLH} /t _{PHL}	Open
tplz/tpzl	Vload
t _{PHZ} /t _{PZH}	GND

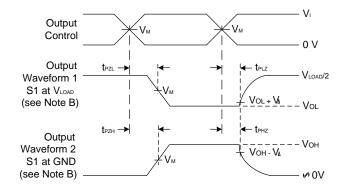
N	Inputs				C	D.	MA
Vcc	VI	t _R /t _F	VM	VLOAD	C∟	RL	VΔ
1.2V	Vcci	≤2ns	V _{CCO} /2	2 x V _{CCO}	15pF	2ΚΩ	0.15V
1.8V±0.15V	V _{CCI}	≤2ns	V _{CCO} /2	2 x V _{CCO}	15pF	2ΚΩ	0.15V
2.5V±0.2V	Vcci	≤2ns	V _{CCO} /2	2 x V _{CCO}	15pF	2ΚΩ	0.15V
3.3V±0.3V	V _{CCI}	≤2.5ns	V _{CCO} /2	$2 \times V_{CCO}$	15pF	2ΚΩ	0.3V



Voltage Waveform Pulse Duration







Voltage Waveform Enable and Disable Times Low and High Level Enabling

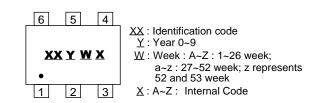
Figure 1 Load Circuit and Voltage Waveforms

- Notes: A. Includes test lead and test apparatus capacitance.
 - B. Waveform 1 is for an output with input set up as a low and device coming out or into 3-state via DIR control. Waveform 2 is for an output with input set up as a high and device coming out or into 3-state via DIR control.
 - C. All pulses are supplied at pulse repetition rate \leq 10 MHz.
 - D. t_{PLZ} and t_{PHZ} are the same as t_{DIS}.
 - E. t_{PZL} and t_{PZH} are the same as t_{EN} .
 - F. t_{PLH} and t_{PHL} are the same as $t_{\text{PD.}}$
 - G. V_{CCI} is the V_{CC} associated with the input.
 - F. V_{CCO} is the V_{CC} associated with the output.



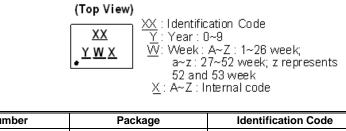
Marking Information

(1) SOT26, SOT363



Part Number	Package	Identification Code
74AVCH1T45W6-7	SOT26	VT
74AVCH1T45DW-7	SOT363	VR

(2) X2-DFN0910-6, X2-DFN1010-6, X2-DFN1410-6, and X2-DFN1409-6



Part Number	Package	Identification Code
74AVCH1T45FW3-7	X2-DFN0910-6	ZR
74AVCH1T45FW5-7	X1-DFN1010-6	VR
74AVCH1T45FX4-7	X2-DFN1409-6	VT
74AVCH1T45FZ4-7	X2-DFN1410-6	VS



Тур

0.05

1.10

0.75

0.38

0.15

3.00

0.95

1.<u>9</u>0

2.80

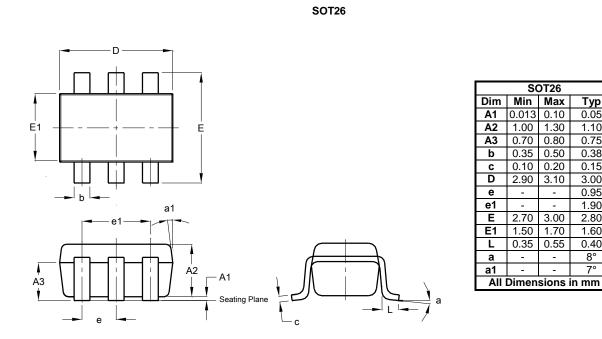
1.60

0.40 8°

7°

Package Outline Dimensions

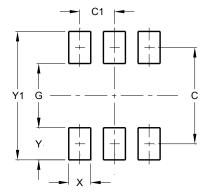
Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26



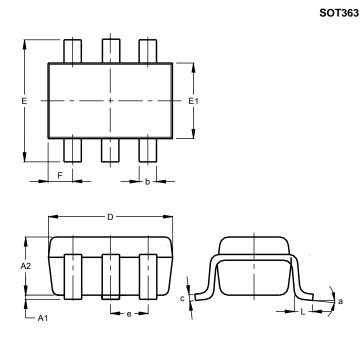
Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20

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Package Outline Dimensions (Cont.)

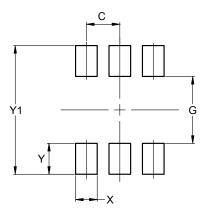
Please see http://www.diodes.com/package-outlines.html for the latest version.



1	60	Taca					
	SOT363						
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	1.00				
b	0.10	0.30	0.25				
С	0.10	0.22	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C).650 E	SC				
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



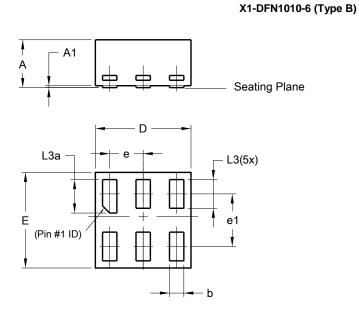
SOT363

Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500



Package Outline Dimensions

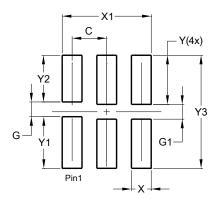
Please see http://www.diodes.com/package-outlines.html for the latest version.



	X1-DFN1010-6 (Type B)					
Dim	Min	Max	Тур			
Α	-	0.50	0.39			
A1	-	0.04	-			
b	0.12	0.20	0.15			
D	0.95	1.050	1.00			
Е	0.95	1.050	1.00			
е	e 0.35 BSC					
e1	-	0.55 B	SC			
L3	0.27	0.30	0.30			
L3a	0.32	0.40	0.35			
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



X1-DFN1010-6 (Type B)

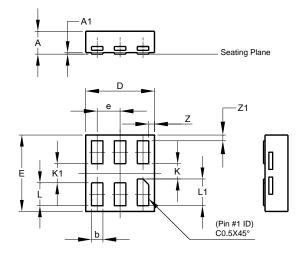
Dimensions	Value
Dimensions	(in mm)
С	0.350
G	0.150
G1	0.150
Х	0.200
X1	0.900
Y	0.500
Y1	0.525
Y2	0.475
Y3	1.150



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

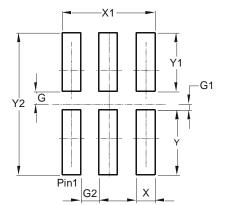




)	X2-DFN0910-6				
Dim	Min	Max	Тур		
Α	-	0.35	0.30		
A1	0	0.03	0.02		
b	0.10	0.20	0.15		
D	0.85	0.95	0.90		
E	0.95	1.05	1.00		
е	-	-	0.30		
K	0.20	-	-		
K1	0.25	-	-		
L	0.25	0.35	0.30		
L1	0.30	0.40	0.35		
Z	-	-	0.075		
Z1	-	-	0.075		
All D	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



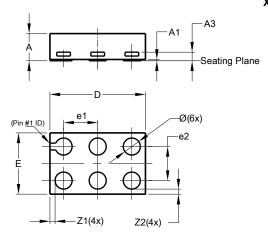
X2-DFN0910-6

Dimensions	Value (in mm)
G	0.100
G1	0.050
G2	0.150
Х	0.150
X1	0.750
Ý	0.525
Y1	0.475
Y2	1.150



Package Outline Dimensions (Cont.)

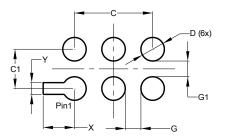
Please see http://www.diodes.com/package-outlines.html for the latest version.



X2-DFN1409-6					
Dim	Min	Max	Тур		
Α	-	0.40	0.39		
A1	0	0.05	0.02		
A3	-	-	0.13		
Ø	0.20	0.30	0.25		
D	1.35	1.45	1.40		
Е	0.85	0.95	0.90		
e1	-	-	0.50		
e2	-	-	0.50		
Z1	-	-	0.075		
Z2	-	-	0.075		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



X2-DFN1409-6

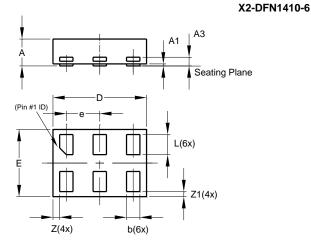
Dimensions	Value	
Dimensions	(in mm)	
С	1.000	
C1	0.500	
D	0.300	
G	0.200	
G1	0.200	
Х	0.400	
Ŷ	0.150	

X2-DFN1409-6



Package Outline Dimensions (Cont.)

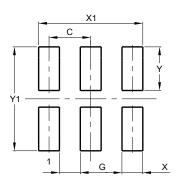
Please see http://www.diodes.com/package-outlines.html for the latest version.



X2-DFN1410-6				
Dim	Min	Max	Тур	
Α	_	0.40	0.39	
A1	0.00	0.05	0.02	
A3	_		0.13	
b	0.15	0.25	0.20	
D	1.35	1.45	1.40	
ш	0.95	1.05	1.00	
e	_		0.50	
L	0.25	0.35	0.30	
Z			0.10	
Z1	0.045	0.105	0.075	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



X2-DFN1410-6

Dimensions	Value (in mm)
С	0.500
G	0.250
Х	0.250
X1	1.250
Y	0.525
Y1	1.250

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